Receipt date: 12/02/2005

10552709 - GAU: 4181



PATENT 8075-1015

## IN THE U.S. PATENT AND TRADEMARK OFFICE

In re application of

Rikizo HATAKEYAMA et al.

Application No. 10/552,709

Filed October 7, 2005

METHOD AND APPARATUS FOR PRODUCING GAS ATOM CONTAINING FULLERENE, AND GAS ATOM CONTAINING FULLERENE

## INFORMATION DISCLOSURE STATEMENT

Assistant Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

December 2, 2005

Sir:

In compliance with Rules 1.97 and 1.98, and in fulfillment of the duty of disclosure under Rule 1.56, the accompanying document, copy of which is attached to this statement, is made of record on the enclosed Form PTO-1449.

A concise explanation of the relevance of this item is that this reference was discovered during any searches they or their client had made, or that they were considered in the preparation of the application.

Respectfully submitted,

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Sheet <u>1</u> of <u>1</u>

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/HMC	OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)  Akihiko FUJII et al., "Photocurrent Enhancement in Conducting Polymer Device by Doping with Endohedral Metallofullerene La@C <sub>82</sub> ," Jpn. J. Appl. Phys., Vol. 41, Pt. 1, No. 4A, (2002), pp. 2254-2255.							
EXAMINER: /Heng M. Chan/			DATE CONSIDERED <sub>02/18/2009</sub>					
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\* Abstract provided for the Examiner's convenience

Y&T December 2, 2005